

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L2	11832	((silicon near on near insulator) (SOI))) and ((silicon near oxide) (silicon near dioxide) ("sio." "sub. 2"))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/10 09:58
L3	292543	(silicon si) near3 (substrate base pad wafer)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/10 09:59
L4	198126	(heat with remov\$3)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/10 10:01
L5	807	2 and 3 and 4	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/10 10:01